New Jersey Semi-Conductor Products, Inc.

20 STERN AVE. SPRINGFIELD, NEW JERSEY 07081 U.S.A.

TELEPHONE: (973) 376-2922

(212) 227-6005

FAX: (973) 376-8960

Advance Information

SWITCHMODE™ Power Rectifier

The SWITCHMODE power rectifier employs the use of the Schottky Barrier principle with a Platinum barrier metal. This state-of-the-art device has the following features:

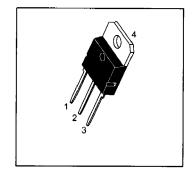
- Dual Diode Construction Terminals 1 and 3 May Be Connected for Parallel Operation at Full Rating
- 45 Volt Blocking Voltage
- Low Forward Voltage Drop
- Guardring for Stress Protection and High dv/dt Capability (> 10 V/ns)
- Guaranteed Reverse Avalanche
- 150°C Operating Junction Temperature

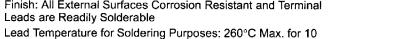
Mechanical Characteristics

- Case: Epoxy, Molded
- Weight: 4.3 grams (approximately)
- Finish: All External Surfaces Corrosion Resistant and Terminal Leads are Readily Solderable
- Seconds
- Shipped 30 Units Per Plastic Tube
- Marking: B6045

MBR6045PT

SCHOTTKY BARRIER RECTIFIER **60 AMPERES** 45 VOLTS





MAXIMUM RATINGS

Rating	Symbol	Max	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	VRRM VRWM VR	45	Volt
Average Rectified Forward Current — Per Diode (Rated V _R) @ T _C = 125°C — Per Device	lF(AV)	30 60	Amp
Peak Repetitive Forward Current, Per Diode (Rated V _R , Square Wave, 20 kHz) @ T _C = 90°C	^I FRM	60	Amp
Non Repetitive Peak Surge Current (Surge applied at rated load conditions halfwave, single phase, 60 Hz)	IFSM	500	Amp
Peak Repetitive Reverse Current (2.0 μs, 1.0 kHz)	RRM	2.0	Amp
Operating Junction Temperature	TJ TJ	-65 to +150	°C
Storage Temperature	T _{stg}	-65 to +175	°C
Peak Surge Junction Temperature (Forward Current Applied)	T _{J(pk)}	175	°C
Voltage Rate of Change	dv/dt	10,000	V/µs

THERMAL CHARACTERISTICS

Thermal Resistance — Junction to Case	$R_{\theta JC}$	1.0	°C/W

NJ Semi-Conductors reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by NJ Semi-Conductors is believed to be both accurate and reliable at the time of going to press. However, NJ Semi-Conductors assumes no responsibility for any errors or omissions discovered in its use. NJ Semi-Conductors encourages customers to verify that datasheets are current before placing orders.

Quality Semi-Conductors

MBR6045PT

ELECTRICAL CHARACTERISTICS

Rating	Symbol	Max	Unit
Instantaneous Forward Voltage (1) @ I _F = 30 Amps, T _C = 25°C @ I _F = 30 Amps, T _C = 125°C @ I _F = 60 Amps, T _C = 25°C	VF	0.62 0.55 0.75	Volts
Instantaneous Reverse Current (1) @ Rated DC Voltage, T _C = 25°C @ Rated DC Voltage, T _C = 100°C	IR	1.0 50	mA

⁽¹⁾ Pulse Test: Pulse Width = 300 μs, Duty Cycle ≤ 2.0%

TYPICAL ELECTRICAL CHARACTERISTICS

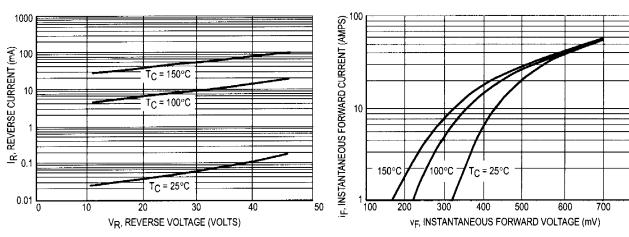
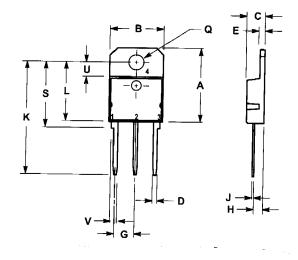


Figure 1. Typical Reverse Current

Figure 2. Typical Forward Voltage

800



- NOTES:

 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

 2. CONTROLLING DIMENSION: MILLIMETER.

	MILLIMETERS		INCHES	
DIM	MIN	MAX	MIN	MAX
Α		20.35		0.801
В	14.70	15.20	0,579	0.598
_ <u>c</u> _	4,70	4.90	0.185	0.193
D	1.10	1.30	0.043	0.051
E	1.17	1.37	0.046	0.054
G	5.40	5.55	0.213	0.219
Н	2.00	3.00	0.079	0.118
J	0.50	0.78	0.020	0.031
K	31.00 REF		1.220 REF	
L		16.20		0.638
Q	4.00	4.10	0.158	0.161
S	17.80	18.20	0.701	0.717
U	4.00 REF		0.157 REF	
٧	1.75 REF		0.069	

TYLE 2:	
PIN 1.	ANODE 1
2.	CATHODE(S
3.	ANODE 2
4	CATHODE(S